# HAMAMATSU

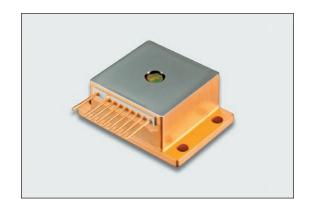
PHOTON IS OUR BUSINESS

### Features

- Emission wavelength: 7.39 µm (Typ.)
- Output power: 20 mW (Min.)
- Threshold current: 1.0 A (Max.)

### Applications

• Trace gas analysis (SO<sub>2</sub>)



### ■ Outline

Quantum Cascade Lasers, using structures of SPC (Single Phonon-Continuum) depopulation and DFB (Distributed Feedback), emit CW (Continuous Wave) mid-IR laser under room temperature.

By controlling the chip's operating temperature through the Peltier element installed in the HHL package, it is possible to tune the emission wavelength without mode hopping while keeping longitudinal single mode operation.

#### Absolute and characteristics

 $T_{op(qcl)}$  = +20 °C, unless otherwise specified.

Parameter	Symbol	Ratings	Unit
Forward current *1	lf	This product has individual difference.	A
Forward voltage *1	Vf	Confirm data sheet attached to a product *2	V
Reverse voltage *1	Vr	0.0	V
Change speed of forward current *3	—	5	mA/s
TEC current (cooling mode) *4	Ŀ	+3.7	A
TEC current (heating mode) *4	IC	-1.5	A
TEC voltage	Vc	±13.0	V
Operating temperature (case) *5*6	T <sub>op(c)</sub>	+10 to +60	O°
Operating temperature (QCL) *7	Top(qcl)	0 to +55	°C
Change speed of operating temperature *8		10	°C/min
Storage temperature *5	T <sub>stg</sub>	-20 to +65	O°

\*1 Confirm data sheet attached to a product. Sensitive to electrical surges and instability. Reverse current/voltage cause damage in laser specifications and out of warranty.

\*2 Necessary specifications of power supply: If  $\ge$  1.3 A, Vf  $\ge$  16 V.

\*3 Speed when changing the forward currrent (If).

\*4 Even if TEC current (I<sub>c</sub>) is below the absolute maximum, insufficient heat dissipation from this product may cause damage in laser and TEC specifications and out of warranty. Especially there are possibilities of damage, degradation and less reliability when TEC is operated in heating mode since heated-up side (laser chip) is thermally isolated from case of package and ambience. Refer to schematic configuration in 3-2-4.

\*5 Avoid water condensation.

\*6 Temperatures of case (body) of HHL-package.

\*7 Temperatures of QC-laser when operated; should be monitored by the built-in thermistor for Top(qcl).

\*8 Speed when changing the operation temperature (Top(qcl)) controlled by the built-in TEC.

## ■ Specifications (laser)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Operating temperature (QCL) *1	T <sub>op(qcl)</sub>	K *2=1354 cm-1	+10		+50	Ο°
Spectral linewidth *3	ΔKL	K *2=1354 cm-1	—	—	0.2 *4	cm⁻¹
Wavenumber tuning range *5	ΔKT	K *2=1354 cm-1	±1.0	—	—	cm-1
Radiant power	$\Phi_{e}$	K *2=1354 cm-1	20	—		mW
Threshold current	I <sub>th</sub>	T <sub>op(qcl)</sub> =+20 °C	—		1.0	A
Side mode suppression ratio	SMSR	Top(qcl)=+20 °C	25 *4	—	—	dB

\*1 This product is able to emit the target wavenumber at a certain  $T_{op(qcl)}$  within the specified temperature range.

\*2 K: Emission wavenumber (cm<sup>-1</sup>).

\*3 WHM.

\*4 These values are limited by resolution and singnal-to-noise ratio of instrument when tested.

\*5 Continuously wavenumber scan range; Center of the tunability range is the emission wavenumber (K).

#### ■ TEC

Parameter	Symbol	Condition	Specification	Unit
Maximum temperature difference	$\Delta T_{max}$	T <sub>h</sub> =27 °C, in N <sub>2</sub> , Q <sub>c</sub> =0, Ic=+3.7 A	>40	Ο°
Maximum heat pumping capacity	Qcmax	T <sub>h</sub> = 27 °C, in N₂, I <sub>c</sub> =+3.7 A, ∆T=0	>18	W
AC resistance	ACR	T <sub>h</sub> =27 °C, 1 kHz	2.5 ± 0.3	Ω

\*  $\Delta T$ : Temperature difference

Qc: Heat pumping capacity

Ic: TEC current

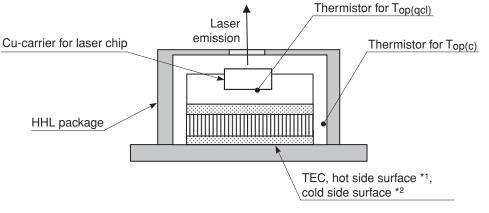
Th: Temperature of TEC's hot side surface (TEC: cooling mode)

### ■ Thermistor

Parameter	Symbol	Condition	Specification	Unit
Resistance	R25	25 °C	10 kΩ ± 2.5 %	—
Beta value	В	0 °C / 100 °C	3450 K	—

\* Same specifications for both thermisters of  $T_{op(qcl)}$  and  $T_{op(c)}$ .

#### Figure 1: Thermistor configurations (schematic)



\*1 when TEC is operated in cooling mode. \*2 when TEC is operated in heating mode.

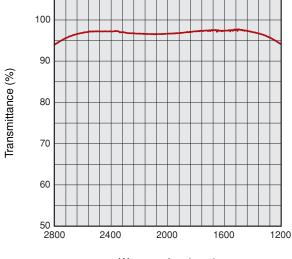
Parameter		Specification	
Material		ZnSe, Plano-Plano	_
Dimension	Clear aperture *1	¢4.4	mm
Thickness		0.7	mm
	Coating	BBAR, both surface	_
Coating	Bandwidth	2500 to 1250	cm <sup>-1</sup>
	Transmittance *2	>96	%

### ■ Window of HHL package

\*1 Mechanical aperture of HHL package.

\*2 Average in the bandwidth.

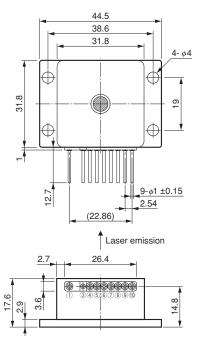
### Figure 2: Typical transmittance curve of the window

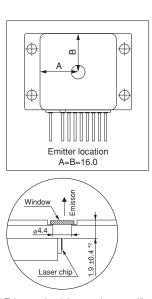


Wavenumber (cm-1)

## ■ Necessary specifications of power supply for the laser (QCL)

Parameter	Specification	
Output current	≥1.3	А
Output voltage	≥16	V
Function	Surge protect	
Function	Constant current control	_





#### Figure 3: Dimensional outline and pin connection (unit: mm)

\*1 Tolerance is ±0.3 mm unless specified. \*2 Edge of QCL chip and outside of the package.

Pin No. *3	Function	Pin No. *3	Function
1	TEC cathode (-)	$\bigcirc$	QCL cathode (-)
3	N.C.	8	Thermistor, (Top(c))
(4)	QCL anode (+)	9	Thermistor, (Top(c))
5	Thermistor, (Top(qcl))	10	TEC anode (+)
6	Thermistor, (Top(qcl))		_

\*3 Pin of ③ is electrically connected to the case; package body. Other all pins are floating to the case.

#### Warning (Class 3B Laser) Invisible laser radiation: Avoid exposure to beam

•The laser radiation emitted from this product is an invisible laser beam that cannot be seen by the human eve. This product falls within "Class 3B Laser" according to IEC 60825-1 laser product classification. Always comply with IEC 60825-1 safety standards when using this product.



Information described in this material current as of October 2023. Specifications are subject to change without notice.

#### HAMAMATSU PHOTONICS K.K. www.hamamatsu.com

#### HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81)53-434-3311, Fax: (81)53-434-5184

T120-1 ICHIMIC-CTIO, HigdStill-KU, HalfitalmatsU City, 435-0536 Jappin, Telephone: (b)93-434-3511, Fax: (b)153-434-3104
US.A: HAMAMATSU CORPORATION: 360 Foothill Road, Bridgewater, NJ 08807, U.S.A., Telephone: (1)908-231-0960, Fax: (1)908-231-0960, Fax: (4)98152-375-0, Fax: (4)98152-255-8
E-mail: info@hamamatsu.com
Germany: HAMAMATSU PHOTONICS DEUTSCHLAND GMBH.: Arzbergerstr. 10, 82211 Herrsching am Ammersee, Germany, Telephone: (4)98152-375-0, Fax: (4)98152-255-8
E-mail: info@hamamatsu.de
France: HAMAMATSU PHOTONICS FRANCE S.A.R.L.: 19 Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: (3)1 69 53 71 10
E-mail: info@hamamatsu.fr
United Kingdom: HAMAMATSU PHOTONICS SCHUTTED: 2 Howard Court, 10 Tewin Road, Welywn Garden City, Hertfordshire, AL7 1BW, UK, Telephone: (44)1707-2324888, Fax: (4)41707-325777
E-mail: info@hamamatsu.com
North Europe: HAMAMATSU PHOTONICS INCLUS SCHUTTED: 2 Howard Court, 10 Tewin Road, Welywn, Garden City, Hertfordshire, AL7 1BW, UK, Telephone: (44)1707-232777
E-mail: info@hamamatsu.com
China: HAMAMATSU PHOTONICS INCLUS SCHULA S.R.L.: Strada della Moia, 1 int, 6 20044 Arese (Milano), Italy, Telephone: (39)02-93 58 17 33, Fax: (39)02-93 58 17 41
E-mail: info@hamamatsu.ed
Erance: HAMAMATSU PHOTONICS (CHILA S.R.L.: Strada della Moia, 1 int, 6 20044 Arese (Milano), Italy, Telephone: (39)02-93 58 17 33, Fax: (39)02-93 58 17 41
E-mail: info@hamamatsu.ed
E-mail: info@hamamatsu.ed
Italy: HAMAMATSU PHOTONICS TALIA S.R.L.: Strada della Moia, 1 int, 6 20044 Arese (Milano), Italy, Telephone: (39)02-93 58 17 33, Fax: (39)02-93 58 17 41
E-mail: info@hamamatsu.ed
Italy: HAMAMATSU PHOTONICS CIALIAS.R.L.: Strada della Moia, 1 int, 6 20044 Arese (Milano), Italy, Telephone: (80)02-695-6006, Fax: (68)0-686-6006, Fax: (68)0-686-6006, Fax: (68)0-680-6006, Fax: (68)0-680-6006, Fax: (68)0-680-6006, Fax: (68)0-680-6006, Fax: (68)-680-6006, Fax: (68)-680-60